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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	PowerPC e300
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	400MHz
Co-Processors/DSP	Communications; QUICC Engine
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	668-BBGA Exposed Pad
Supplier Device Package	668-PBGA-PGE (29x29)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/kmpc8358zqagdga

- Data bus widths:
  - Single 32-bit data PCI interface that operates at up to 66 MHz
- PCI 3.3-V compatible (not 5-V compatible)
- PCI host bridge capabilities on both interfaces
- PCI agent mode supported on PCI interface
- Support for PCI-to-memory and memory-to-PCI streaming
- Memory prefetching of PCI read accesses and support for delayed read transactions
- Support for posting of processor-to-PCI and PCI-to-memory writes
- On-chip arbitration, supporting five masters on PCI
- Support for accesses to all PCI address spaces
- Parity support
- Selectable hardware-enforced coherency
- Address translation units for address mapping between host and peripheral
- Dual address cycle supported when the device is the target
- Internal configuration registers accessible from PCI

- Local bus controller (LBC)
  - Multiplexed 32-bit address and data operating at up to 133 MHz
  - Eight chip selects support eight external slaves
  - Up to eight-beat burst transfers
  - 32-, 16-, and 8-bit port sizes are controlled by an on-chip memory controller
  - Three protocol engines available on a per chip select basis:
    - General-purpose chip select machine (GPCM)
    - Three user programmable machines (UPMs)
    - Dedicated single data rate SDRAM controller
  - Parity support
  - Default boot ROM chip select with configurable bus width (8-, 16-, or 32-bit)
- Programmable interrupt controller (PIC)
  - Functional and programming compatibility with the MPC8260 interrupt controller
  - Support for 8 external and 35 internal discrete interrupt sources
  - Support for one external (optional) and seven internal machine checkstop interrupt sources
  - Programmable highest priority request
  - Four groups of interrupts with programmable priority
  - External and internal interrupts directed to communication processor
  - Redirects interrupts to external $\overline{\text{INTA}}$ pin when in core disable mode
  - Unique vector number for each interrupt source
- Dual industry-standard I^2C interfaces
  - Two-wire interface

  - Multiple master support
  - Master or slave I^2C mode support
  - On-chip digital filtering rejects spikes on the bus
  - System initialization data is optionally loaded from I^2C-1 EPROM by boot sequencer embedded hardware
- DMA controller
  - Four independent virtual channels
  - Concurrent execution across multiple channels with programmable bandwidth control
  - All channels accessible by local core and remote PCI masters
  - Misaligned transfer capability
  - Data chaining and direct mode
  - Interrupt on completed segment and chain
  - DMA external handshake signals: $\overline{\text{DMA\_DREQ}}$[0:3]/$\overline{\text{DMA\_DACK}}$[0:3]/$\overline{\text{DMA\_DONE}}$[0:3]. There is one set for each DMA channel. The pins are multiplexed to the parallel IO pins with other QE functions.
- DUART
  - Two 4-wire interfaces (RxD, TxD, RTS, CTS)
  - Programming model compatible with the original 16450 UART and the PC16550D
- System timers
  - Periodic interrupt timer
  - Real-time clock
  - Software watchdog timer
  - Eight general-purpose timers
- IEEE Std. 1149.1™-compliant, JTAG boundary scan
- Integrated PCI bus and SDRAM clock generation

2 Electrical Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC8358E. The device is currently targeted to these specifications. Some of these specifications are independent of the I/O cell, but are included for a more complete reference. These are not purely I/O buffer design specifications.

Table 5 shows the estimated typical I/O power dissipation for the device.

Table 5. Estimated Typical I/O Power Dissipation

Interface	Parameter	GV_{DD} (1.8 V)	GV_{DD} (2.5 V)	OV_{DD} (3.3 V)	LV_{DD} (3.3 V)	LV_{DD} (2.5 V)	Unit	Comments
DDR I/O 65% utilization 2.5 V R_s = 20 Ω R_t = 50 Ω 2 pairs of clocks	200 MHz, 1x32 bits	0.3	0.46	—	—	—	W	—
	200 MHz, 1x64 bits	0.4	0.58	—	—	—	W	—
	200 MHz, 2x32 bits	0.6	0.92	—	—	—	W	—
	266 MHz, 1x32 bits	0.35	0.56	—	—	—	W	—
	266 MHz, 1x64 bits	0.46	0.7	—	—	—	W	—
	266 MHz, 2x32 bits	0.7	1.11	—	—	—	W	—
Local Bus I/O Load = 25 pf 3 pairs of clocks	133 MHz, 32 bits	—	—	0.22	—	—	W	—
	83 MHz, 32 bits	—	—	0.14	—	—	W	—
	66 MHz, 32 bits	—	—	0.12	—	—	W	—
	50 MHz, 32 bits	—	—	0.09	—	—	W	—
PCI I/O Load = 30 pF	33 MHz, 32 bits	—	—	0.05	—	—	W	—
	66 MHz, 32 bits	—	—	0.07	—	—	W	—
10/100/1000 Ethernet I/O Load = 20 pF	MII or RMII	—	—	—	0.01	—	W	Multiply by number of interfaces used.
	GMII or TBI	—	—	—	0.04	—	W	
	RGMII or RTBI	—	—	—	—	0.04	W	
Other I/O	—	—	—	0.1	—	—	W	—

4 Clock Input Timing

This section provides the clock input DC and AC electrical characteristics for the MPC8358E.

NOTE

The rise/fall time on QUICC Engine block input pins should not exceed 5 ns. This should be enforced especially on clock signals. Rise time refers to signal transitions from 10% to 90% of V_{DD}; fall time refers to transitions from 90% to 10% of V_{DD}.

Table 12. QUICC Engine Block Operating Frequency Limitations (continued)

Interface	Interface Operating Frequency (MHz)	Max Interface Bit Rate (Mbps)	Min QUICC Engine Operating Frequency[1] (MHz)	Notes
UART/async HDLC	3.68 (max internal ref clock)	115 (Kbps)	20	—
BISYNC	2 (max)	2	20	—
USB	48 (ref clock)	12	96	—

Notes:
1. The QUICC Engine module needs to run at a frequency higher than or equal to what is listed in this table.
2. 'F' is the actual interface operating frequency.
3. The bit rate limit is independent of the data bus width (that is, the same for serial, nibble, or octal interfaces).
4. TDM in high-speed mode for serial data interface.

6 DDR and DDR2 SDRAM

This section describes the DC and AC electrical specifications for the DDR and DDR2 SDRAM interface of the MPC8358E.

6.1 DDR and DDR2 SDRAM DC Electrical Characteristics

Table 13 provides the recommended operating conditions for the DDR2 SDRAM component(s) of the device when GV_{DD}(typ) = 1.8 V.

Table 13. DDR2 SDRAM DC Electrical Characteristics for GV_{DD}(typ) = 1.8 V

Parameter/Condition	Symbol	Min	Max	Unit	Notes
I/O supply voltage	GV_{DD}	1.71	1.89	V	1
I/O reference voltage	MV_{REF}	$0.49 \times GV_{DD}$	$0.51 \times GV_{DD}$	V	2
I/O termination voltage	V_{TT}	$MV_{REF} - 0.04$	$MV_{REF} + 0.04$	V	3
Input high voltage	V_{IH}	$MV_{REF} + 0.125$	$GV_{DD} + 0.3$	V	—
Input low voltage	V_{IL}	–0.3	$MV_{REF} - 0.125$	V	—
Output leakage current	I_{OZ}	—	±10	µA	4
Output high current (V_{OUT} = 1.420 V)	I_{OH}	–13.4	—	mA	—
Output low current (V_{OUT} = 0.280 V)	I_{OL}	13.4	—	mA	—
MV_{REF} input leakage current	I_{VREF}	—	±10	µA	—

Table 19. DDR and DDR2 SDRAM Input AC Timing Specifications Mode

At recommended operating conditions with GV_{DD} of (1.8 or 2.5 V) ± 5%.

Parameter	Symbol	Min	Max	Unit	Notes
MDQS—MDQ/MECC input skew per byte 266 MHz 200 MHz	t_{DISKEW}	 –1125 –1250	 1125 1250	ps	1, 2

Notes:
1. AC timing values are based on the DDR data rate, which is twice the DDR memory bus frequency.
2. Maximum possible skew between a data strobe (MDQS[n]) and any corresponding bit of data (MDQ[8n + {0...7}] if 0 ≤ n ≤ 7) or ECC (MECC[{0...7}] if n = 8).

Figure 5 shows the input timing diagram for the DDR controller.

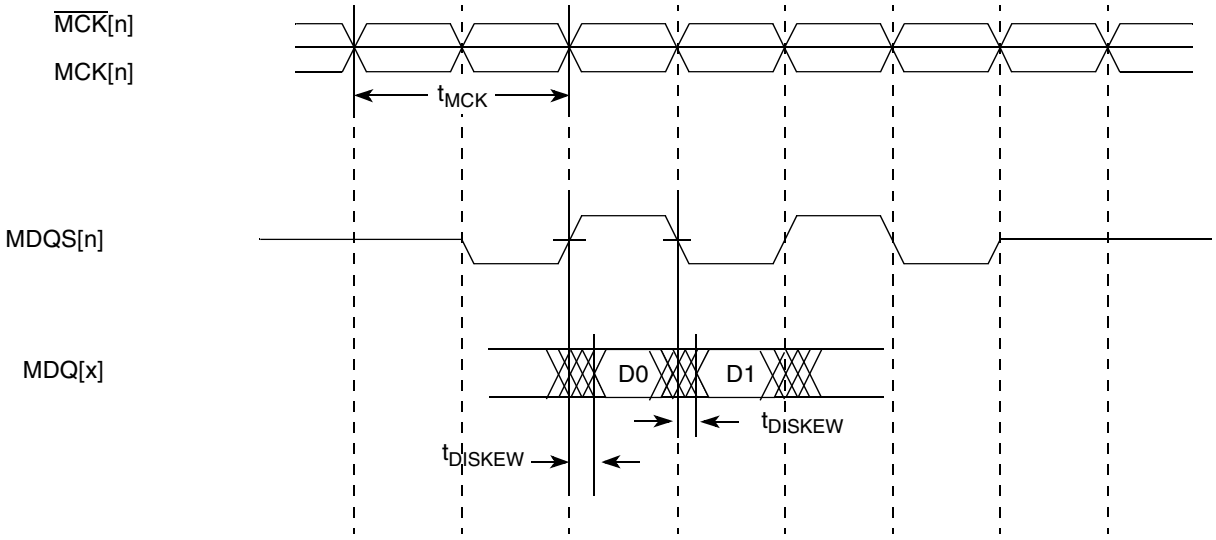


Figure 5. DDR Input Timing Diagram

6.2.2 DDR and DDR2 SDRAM Output AC Timing Specifications

Table 20 and Table 21 provide the output AC timing specifications and measurement conditions for the DDR and DDR2 SDRAM interface.

Table 20. DDR and DDR2 SDRAM Output AC Timing Specifications for Source Synchronous Mode

At recommended operating conditions with GV_{DD} of (1.8 V or 2.5 V) ± 5%.

Parameter[8]	Symbol[1]	Min	Max	Unit	Notes
MCK[n] cycle time, (MCK[n]/$\overline{\text{MCK}}$[n] crossing)	t_{MCK}	6	10	ns	2
Skew between any MCK to ADDR/CMD 266 MHz 200 MHz	t_{AOSKEW}	 –1.1 –1.2	 0.3 0.4	ns	3

Figure 11 shows the MII transmit AC timing diagram.

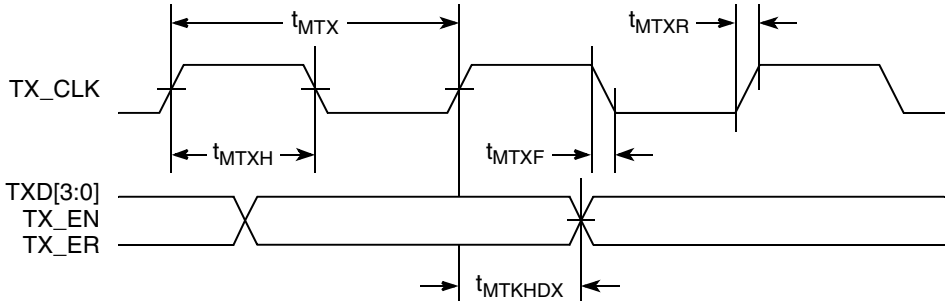


Figure 11. MII Transmit AC Timing Diagram

8.2.2.2 MII Receive AC Timing Specifications

Table 29 provides the MII receive AC timing specifications.

Table 29. MII Receive AC Timing Specifications

At recommended operating conditions with LV_{DD}/OV_{DD} of 3.3 V ± 10%.

Parameter/Condition	Symbol[1]	Min	Typ	Max	Unit
RX_CLK clock period 10 Mbps	t_{MRX}	—	400	—	ns
RX_CLK clock period 100 Mbps	t_{MRX}	—	40	—	ns
RX_CLK duty cycle	t_{MRXH}/t_{MRX}	35	—	65	%
RXD[3:0], RX_DV, RX_ER setup time to RX_CLK	t_{MRDVKH}	10.0	—	—	ns
RXD[3:0], RX_DV, RX_ER hold time to RX_CLK	t_{MRDXKH}	10.0	—	—	ns
RX_CLK clock rise time, (20% to 80%)	t_{MRXR}	1.0	—	4.0	ns
RX_CLK clock fall time, (80% to 20%)	t_{MRXF}	1.0	—	4.0	ns

Note:

1. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{MRDVKH} symbolizes MII receive timing (MR) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{MRX} clock reference (K) going to the high (H) state or setup time. Also, t_{MRDXKL} symbolizes MII receive timing (GR) with respect to the time data input signals (D) went invalid (X) relative to the t_{MRX} clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{MRX} represents the MII (M) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 12 provides the AC test load.

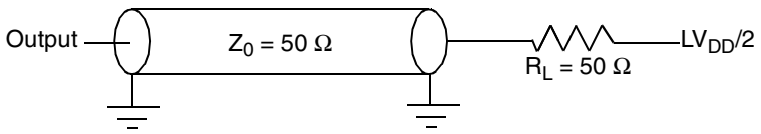


Figure 12. AC Test Load

Table 40. Local Bus General Timing Parameters—DLL Bypass Mode (continued)

Parameter	Symbol[1]	Min	Max	Unit	Notes
Local bus clock to output high impedance for LAD/LDP	t_{LBKHOZ}	—	4	ns	—

Notes:

1. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, $t_{LBIXKH1}$ symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the t_{LBK} clock reference (K) goes high (H), in this case for clock one (1). Also, t_{LBKHOX} symbolizes local bus timing (LB) for the t_{LBK} clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.
2. All timings are in reference to falling edge of LCLK0 (for all outputs and for $\overline{\text{LGTA}}$ and LUPWAIT inputs) or rising edge of LCLK0 (for all other inputs).
3. All signals are measured from $OV_{DD}/2$ of the rising/falling edge of LCLK0 to $0.4 \times OV_{DD}$ of the signal in question for 3.3-V signaling levels.
4. Input timings are measured at the pin.
5. $t_{LBOTOT1}$ should be used when RCWH[LALE] is not set and when the load on LALE output pin is at least 10 pF less than the load on LAD output pins.
6. $t_{LBOTOT2}$ should be used when RCWH[LALE] is set and when the load on LALE output pin is at least 10 pF less than the load on LAD output pins.
7. $t_{LBOTOT3}$ should be used when RCWH[LALE] is set and when the load on LALE output pin equals to the load on LAD output pins.
8. For purposes of active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
9. DLL bypass mode is not recommended for use at frequencies above 66 MHz.

Figure 21 provides the AC test load for the local bus.

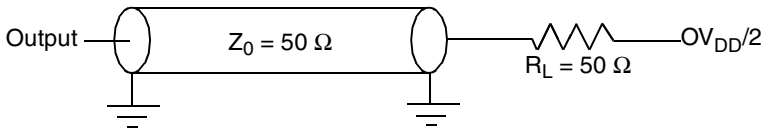


Figure 21. Local Bus C Test Load

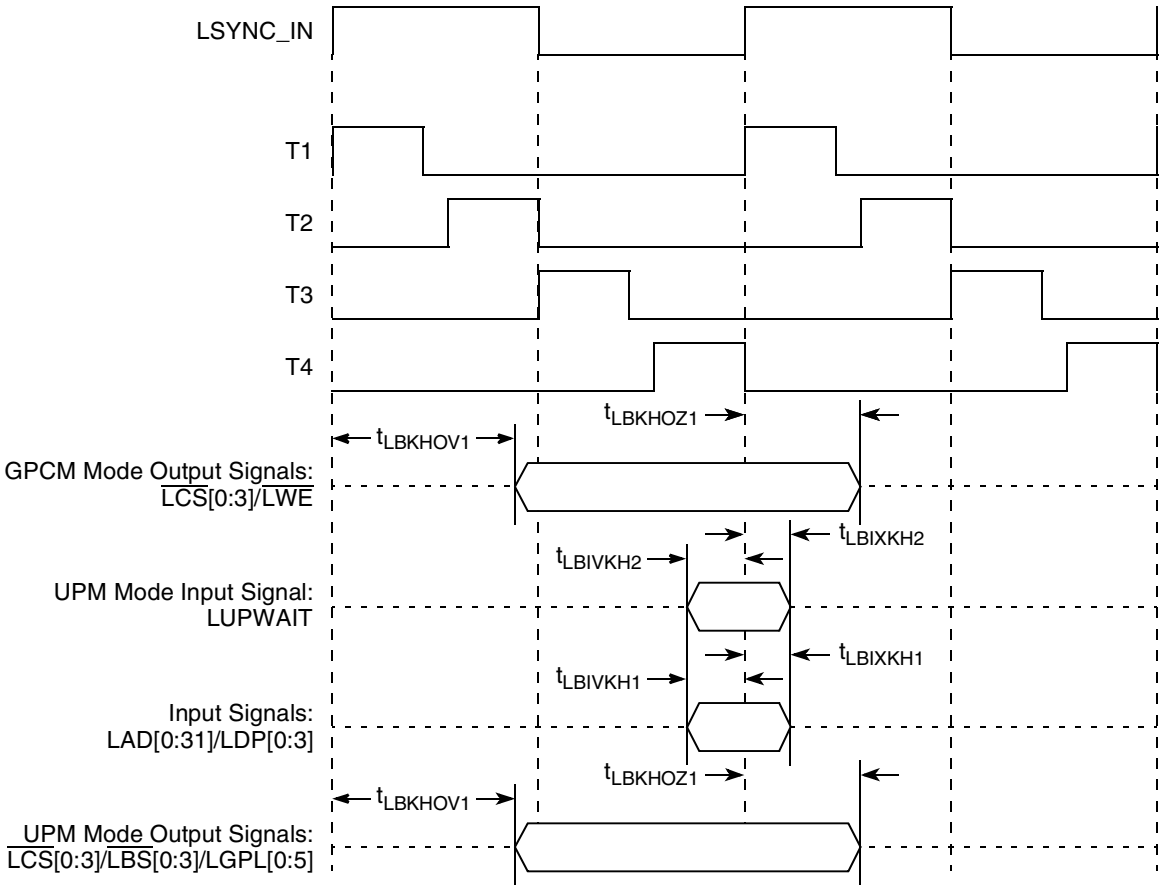


Figure 27. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4 (DLL Enabled)

10 JTAG

This section describes the DC and AC electrical specifications for the IEEE 1149.1 (JTAG) interface of the MPC8358E.

10.1 JTAG DC Electrical Characteristics

Table 41 provides the DC electrical characteristics for the IEEE 1149.1 (JTAG) interface of the device.

Table 41. JTAG interface DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	V_{OH}	I_{OH} = –6.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 6.0 mA	—	0.5	V
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V
Input high voltage	V_{IH}	—	2.5	OV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	$0 V \le V_{IN} \le OV_{DD}$	—	±10	μA

10.2 JTAG AC Electrical Characteristics

This section describes the AC electrical specifications for the IEEE 1149.1 (JTAG) interface of the device.

Table 42 provides the JTAG AC timing specifications as defined in Figure 29 through Figure 32.

Table 42. JTAG AC Timing Specifications (Independent of CLKIN)[1]

At recommended operating conditions (see Table 2).

Parameter	Symbol [2]	Min	Max	Unit	Notes
JTAG external clock frequency of operation	f_{JTG}	0	33.3	MHz	—
JTAG external clock cycle time	t_{JTG}	30	—	ns	—
JTAG external clock duty cycle	t_{JTKHKL}/t_{JTG}	45	55	%	—
JTAG external clock rise and fall times	t_{JTGR} & t_{JTGF}	0	2	ns	—
$\overline{\text{TRST}}$ assert time	t_{TRST}	25	—	ns	3
Input setup times: Boundary-scan data TMS, TDI	 t_{JTDVKH} t_{JTIVKH}	 4 4	 — —	ns	 4
Input hold times: Boundary-scan data TMS, TDI	 t_{JTDXKH} t_{JTIXKH}	 10 10	 — —	ns	 4
Valid times: Boundary-scan data TDO	 t_{JTKLDV} t_{JTKLOV}	 2 2	 11 11	ns	 5
Output hold times: Boundary-scan data TDO	 t_{JTKLDX} t_{JTKLOX}	 2 2	 — —	ns	 5
JTAG external clock to output high impedance: Boundary-scan data TDO	 t_{JTKLDZ} t_{JTKLOZ}	 2 2	 19 9	ns	 5, 6 6

Notes:

1. All outputs are measured from the midpoint voltage of the falling/rising edge of t_{TCLK} to the midpoint of the signal in question. The output timings are measured at the pins. All output timings assume a purely resistive 50-Ω load (see Figure 21). Time-of-flight delays must be added for trace lengths, vias, and connectors in the system.
2. The symbols used for timing specifications herein follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state) (reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{JTDVKH} symbolizes JTAG device timing (JT) with respect to the time data input signals (D) reaching the valid state (V) relative to the t_{JTG} clock reference (K) going to the high (H) state or setup time. Also, t_{JTDXKH} symbolizes JTAG timing (JT) with respect to the time data input signals (D) went invalid (X) relative to the t_{JTG} clock reference (K) going to the high (H) state. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
3. $\overline{\text{TRST}}$ is an asynchronous level sensitive signal. The setup time is for test purposes only.
4. Non-JTAG signal input timing with respect to t_{TCLK}.
5. Non-JTAG signal output timing with respect to t_{TCLK}.
6. Guaranteed by design and characterization.

Figure 38 provides the AC test load for the timers.

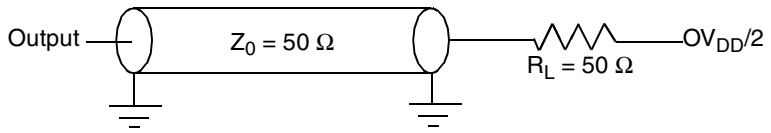


Figure 38. Timers AC Test Load

14 GPIO

This section describes the DC and AC electrical specifications for the GPIO of the MPC8358E.

14.1 GPIO DC Electrical Characteristics

Table 50 provides the DC electrical characteristics for the device GPIO.

Table 50. GPIO DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit	Notes
Output high voltage	V_{OH}	I_{OH} = –6.0 mA	2.4	—	V	1
Output low voltage	V_{OL}	I_{OL} = 6.0 mA	—	0.5	V	1
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V	1
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V	1
Input low voltage	V_{IL}	—	–0.3	0.8	V	—
Input current	I_{IN}	0 V ≤ V_{IN} ≤ OV_{DD}	—	±10	μA	—

Note: This specification applies when operating from 3.3-V supply.

14.2 GPIO AC Timing Specifications

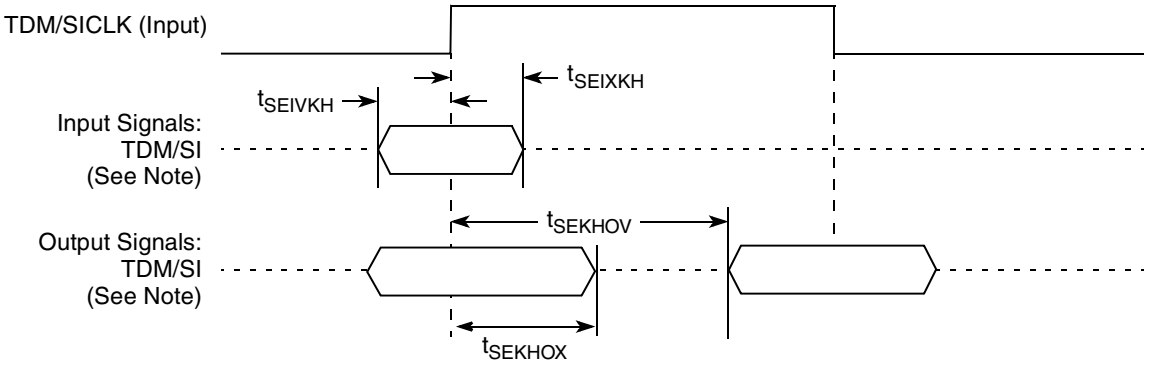
Table 51 provides the GPIO input and output AC timing specifications.

Table 51. GPIO Input AC Timing Specifications[1]

Characteristic	Symbol[2]	Typ	Unit
GPIO inputs—minimum pulse width	t_{PIWID}	20	ns

Notes:
1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.
2. GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs should be synchronized before use by any external synchronous logic. GPIO inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation.

Figure 44 shows the TDM/SI timing with external clock.



Note: The clock edge is selectable on TDM/SI

Figure 44. TDM/SI AC Timing (External Clock) Diagram

18 UTOPIA/POS

This section describes the DC and AC electrical specifications for the UTOPIA/POS of the MPC8358E.

18.1 UTOPIA/POS DC Electrical Characteristics

Table 58 provides the DC electrical characteristics for the device UTOPIA.

Table 58. UTOPIA DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	V_{OH}	I_{OH} = –8.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 8.0 mA	—	0.5	V
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	0 V ≤ V_{IN} ≤ OV_{DD}	—	±10	µA

18.2 UTOPIA/POS AC Timing Specifications

Table 59 provides the UTOPIA input and output AC timing specifications.

Table 59. UTOPIA AC Timing Specifications[1]

Characteristic	Symbol[2]	Min	Max	Unit	Notes
UTOPIA outputs—Internal clock delay	t_{UIKHOV}	0	11.5	ns	—
UTOPIA outputs—External clock delay	t_{UEKHOV}	1	11.6	ns	—
UTOPIA outputs—Internal clock high impedance	t_{UIKHOX}	0	8.0	ns	—
UTOPIA outputs—External clock high impedance	t_{UEKHOX}	1	10.0	ns	—
UTOPIA inputs—Internal clock input setup time	t_{UIIVKH}	6	—	ns	—

Figure 47 shows the UTOPIA timing with internal clock.

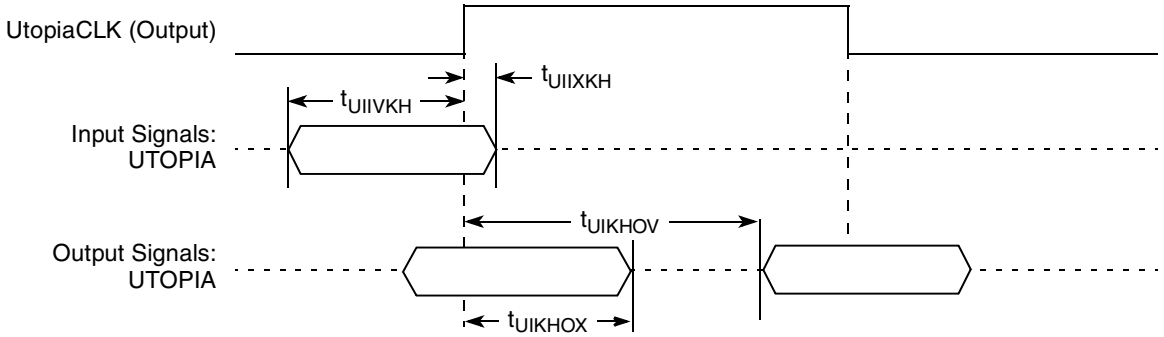


Figure 47. UTOPIA AC Timing (Internal Clock) Diagram

19 HDLC, BISYNC, Transparent, and Synchronous UART

This section describes the DC and AC electrical specifications for the high level data link control (HDLC), BISYNC, transparent, and synchronous UART protocols of the MPC8358E.

19.1 HDLC, BISYNC, Transparent, and Synchronous UART DC Electrical Characteristics

Table 60 provides the DC electrical characteristics for the device HDLC, BISYNC, transparent, and synchronous UART protocols.

Table 60. HDLC, BISYNC, Transparent, and Synchronous UART DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	V_{OH}	I_{OH} = –2.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.5	V
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	0 V ≤ V_{IN} ≤ OV_{DD}	—	±10	μA

Figure 48 provides the AC test load.

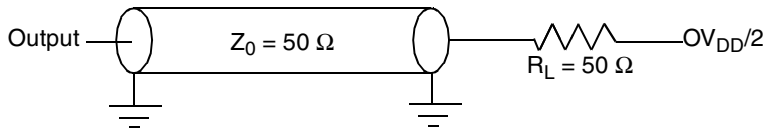
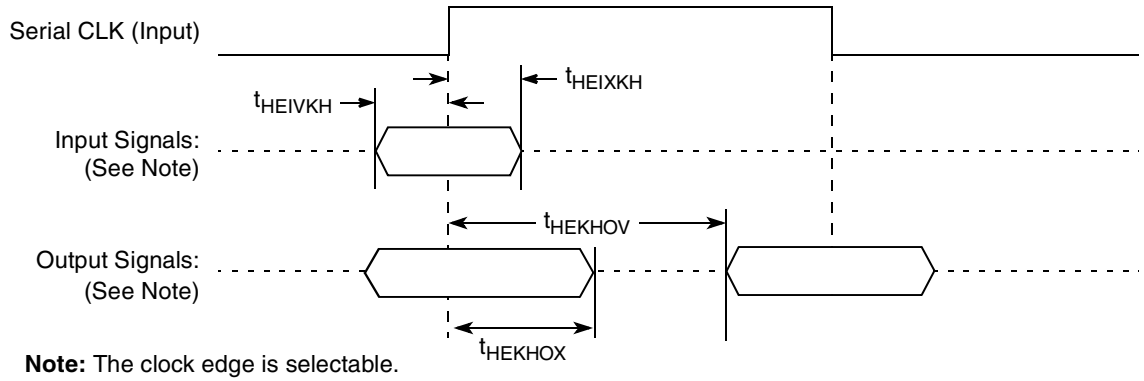


Figure 48. AC Test Load

19.3 AC Test Load

Figure 49 and Figure 50 represent the AC timing from Table 61 and Table 62. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

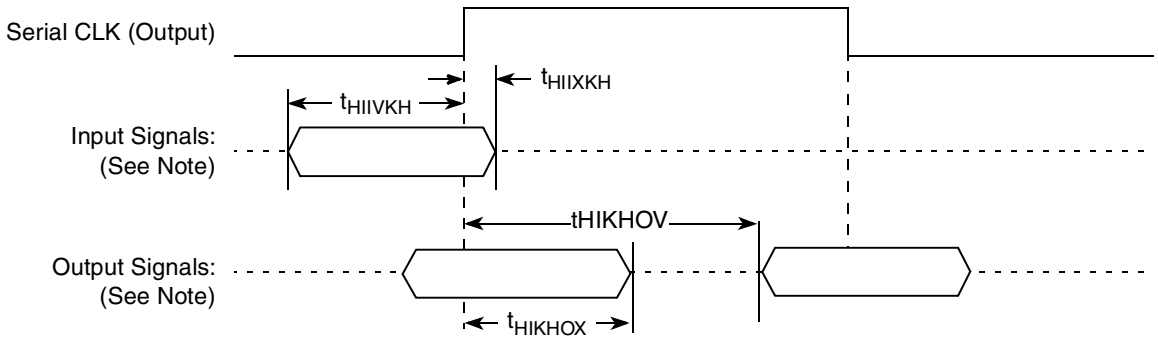
Figure 49 shows the timing with external clock.



Note: The clock edge is selectable.

Figure 49. AC Timing (External Clock) Diagram

Figure 50 shows the timing with internal clock.



Note: The clock edge is selectable.

Figure 50. AC Timing (Internal Clock) Diagram

4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
5. Parallelism measurement must exclude any effect of mark on top surface of package.
6. Distance from the seating plane to the encapsulant material.

21.3 Pinout Listings

Refer to AN3097, “MPC8360/MPC8358E PowerQUICC Design Checklist,” for proper pin termination and usage.

Table 65 shows the pin list of the MPC8358E PBGA package.

Table 65. MPC8358E PBGA Pinout Listing

Signal	Package Pin Number	Pin Type	Power Supply	Notes
DDR SDRAM Memory Controller Interface				
MEMC_MDQ[0:63]	AD20, AG24, AF24, AH24, AF23, AE22, AH26, AD21, AH25, AD22, AF27, AB24, AG25, AC22, AE25, AC24, AD25, AB25, AC25, AG28, AD26, AE23, AG26, AC26, AD27, V25, AA28, AA25, Y26, W27, U24, W24, E28, H24, E26, D25, G27, H25, G26, F26, F27, F25, D26, F24, G25, E27, D27, C28, C27, F22, B26, F21, B28, E22, D24, C24, A25, E20, F20, D20, A23, C21, C23, E19	I/O	GV_{DD}	—
MEMC_MECC[0:7]	N26, N24, J26, H28, N28, P24, L26, K24	I/O	GV_{DD}	—
MEMC_MDM[0:8]	AG23, AD23, AE26, V28, G28, D28, D23, B24, U27	O	GV_{DD}	—
MEMC_MDQS[0:8]	AH23, AH27, AF28, T28, H26, E25, B25, A24, R28	I/O	GV_{DD}	—
MEMC_MBA[0:2]	V26, W28, Y28	O	GV_{DD}	—
MEMC_MA[0:14]	L25, M25, M24, K28, P28, T24, M27, R25, P25, L28, U26, M28, L27, K27, H27	O	GV_{DD}	—
MEMC_MODT[0:3]	AE21, AC19, E23, B23	—	GV_{DD}	6
$\overline{\text{MEMC\_MWE}}$	R27	O	GV_{DD}	—
$\overline{\text{MEMC\_MRAS}}$	W25	O	GV_{DD}	—
$\overline{\text{MEMC\_MCAS}}$	R24	O	GV_{DD}	—
$\overline{\text{MEMC\_MCS}}$[0:3]	T26, U28, J25, F28	O	GV_{DD}	—
MEMC_MCKE[0:1]	AD24, AE28	O	GV_{DD}	—
MEMC_MCK[0:5]	AG22, AG27, A26, C26, P26, E21	O	GV_{DD}	—
$\overline{\text{MEMC\_MCK}}$[0:5]	AF22, AF26, A27, B27, N27, D22	O	GV_{DD}	—
MDIC[0:1]	F19, AA27	I/O	GV_{DD}	11
PCI				
$\overline{\text{PCI\_INTA}}$/ PF[5]	R3	I/O	$LV_{DD}2$	2
$\overline{\text{PCI\_RESET\_OUT}}$/ PF[6]	P6	I/O	$LV_{DD}2$	—
PCI_AD[0:31]/ PG[0:31]	AB5, AC5, AG1, AA5, AF2, AD4, Y6, AF1, AE2, AC4, AD3, AE1, Y4, AC3, AD2, AD1, AB2, Y3, AA1, Y1, W1, V6, W3, V4, T5, W2, V5, V1, U4, V2, U2, T2	I/O	$LV_{DD}2$	—
$\overline{\text{PCI\_C\_BE}}$[0:3]/ PF[7:10]	Y5, AC2, Y2, U5	I/O	OV_{DD}	—

Table 65. MPC8358E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
LGPL2/ LSDRAS/ LOE	AH19	O	OV_{DD}	—
LGPL3/ LSDCAS/ cfg_reset_source2	AE18	I/O	OV_{DD}	—
LGPL4/ LGTA/ LUPWAIT/ LPBSE	AG19	I/O	OV_{DD}	—
LGPL5/ cfg_clkin_div	AF19	I/O	OV_{DD}	—
LCKE	AD8	O	OV_{DD}	—
LCLK[0]	AC9	O	OV_{DD}	—
LCLK[1]/ LCS[6]	AG6	O	OV_{DD}	—
LCLK[2]/ LCS[7]	AE7	O	OV_{DD}	—
LSYNC_OUT	AG4	O	OV_{DD}	—
LSYNC_IN	AC8	I	OV_{DD}	—
Programmable Interrupt Controller				
MCP_OUT	AG3	O	OV_{DD}	2
IRQ0/ MCP_IN	AH4	I	OV_{DD}	—
IRQ[1:2]	AG5, AH5	I/O	OV_{DD}	—
IRQ[3]/ CORE_SRESET	AD7	I/O	OV_{DD}	—
IRQ[4:5]	AC7, AD6	I/O	OV_{DD}	—
IRQ[6:7]	AC6, AC10	I/O	OV_{DD}	—
DUART				
UART1_SOUT	AE3	O	OV_{DD}	—
UART1_SIN	AE4	I/O	OV_{DD}	—
UART1_CTS	AG2	I/O	OV_{DD}	—
UART1_RTS	AA6	O	OV_{DD}	—
I^2C Interface				
IIC1_SDA	AB6	I/O	OV_{DD}	2
IIC1_SCL	AD5	I/O	OV_{DD}	2
IIC2_SDA	AF3	I/O	OV_{DD}	2
IIC2_SCL	AH2	I/O	OV_{DD}	2
QUICC Engine				
CE_PA[0]	F6	I/O	$LV_{DD}0$	—

Table 65. MPC8358E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GV_{DD}	C19, C22, C25, G24, J18, J19, J20, J24, K19, K20, K26, L20, M20, M26, N19, N20, P20, P27, R20, T19, T20, T27, U19, U20, U25, V19, V20, W20, W26, Y20, AA24, AB28, AC21, AC28, AD28, AF21, AF25	Power for DDR DRAM I/O Voltage (2.5 V or 1.8 V)	GV_{DD}	—
$LV_{DD}0$	F3, J9	—	$LV_{DD}0$	—
$LV_{DD}1$	P3, P10	—	$LV_{DD}1$	10
$LV_{DD}2$	R4, R10	—	$LV_{DD}2$	10
V_{DD}	M12, M13, M16, M17, N10, N12, N13, N14, N15, N16, N17, P12, P13, P14, P15, P16, P17, R12, R13, R16, R17, T12, T13, T16, T17, U12, U13, U14, U15, U16, U17, V12, V13, V16, V17, W11, W12, W13, W15, W16, W17, Y16, Y17	Power for Core (1.2 V)	V_{DD}	—
OV_{DD}	C6, C12, D17, J11, J13, J14, K3, K9, K10, K12, K15, K16, L10, M9, N9, T9, U9, V3, V10, W9, W10, W14, Y9, Y10, Y12, Y13, Y15, AA3, AE6, AE16, AF11, AF20	PCI, 10/100 Ethernet, and other Standard (3.3 V)	OV_{DD}	—
MVREF1	J27	I	DDR Reference Voltage	—
MVREF2	Y24	I	DDR Reference Voltage	—
No Connect				
NC	F23, G23, H23, J23, K23, L23, M23, N23, P23, R23, T23, U23, V23, W23, Y23, AA23, AB23, AC23	—	—	—

Notes:
1. This pin is an open drain signal. A weak pull-up resistor (1 kΩ) should be placed on this pin to OV_{DD}.
2. This pin is an open drain signal. A weak pull-up resistor (2–10 kΩ) should be placed on this pin to OV_{DD}.
3. This output is actively driven during reset rather than being three-stated during reset.
4. These JTAG pins have weak internal pull-up P-FETs that are always enabled.
5. This pin should have a weak pull up if the chip is in PCI host mode. Follow PCI specifications recommendation.
6. These are On Die Termination pins, used to control DDR2 memories internal termination resistance.
7. This pin must always be tied to GND.
8. This pin must always be left not connected.
9. This pin must always be tied to GV_{DD}.
10. Refers to *MPC8360E PowerQUICC II™ Pro Integrated Communications Processor Reference Manual* section on “RGMII Pins” for information about the two UCC2 Ethernet interface options.
11. It is recommended that MDIC0 be tied to GND using an 18.2 Ω resistor and MDIC1 be tied to DDR power using an 18.2 Ω resistor for DDR2.

22.1 System PLL Configuration

The system PLL is controlled by the RCWL[SPMF] and RCWL[SVCOD] parameters. Table 68 shows the multiplication factor encodings for the system PLL.

Table 68. System PLL Multiplication Factors

RCWL[SPMF]	System PLL Multiplication Factor
0000	× 16
0001	Reserved
0010	× 2
0011	× 3
0100	× 4
0101	× 5
0110	× 6
0111	× 7
1000	× 8
1001	× 9
1010	× 10
1011	× 11
1100	× 12
1101	× 13
1110	× 14
1111	× 15

The RCWL[SVCOD] denotes the system PLL VCO internal frequency as shown in Table 69.

Table 69. System PLL VCO Divider

RCWL[SVCOD]	VCO Divider
00	4
01	8
10	2
11	Reserved

NOTE

The VCO divider must be set properly so that the system VCO frequency is in the range of 600–1400 MHz.

Table 76 shows heat sinks and junction-to-ambient thermal resistance for PBGA package.

Table 76. Heat Sinks and Junction-to-Ambient Thermal Resistance of PBGA Package

Heat Sink Assuming Thermal Grease	Air Flow	29 × 29 mm PBGA
		Thermal Resistance
AAVID 30 × 30 × 9.4 mm Pin Fin	Natural Convection	12.6
AAVID 30 × 30 × 9.4 mm Pin Fin	1 m/s	8.2
AAVID 30 × 30 × 9.4 mm Pin Fin	2 m/s	7.0
AAVID 31 × 35 × 23 mm Pin Fin	Natural Convection	10.5
AAVID 31 × 35 × 23 mm Pin Fin	1 m/s	6.6
AAVID 31 × 35 × 23 mm Pin Fin	2 m/s	6.1
Wakefield, 53 × 53 × 25 mm Pin Fin	Natural Convection	9.0
Wakefield, 53 × 53 × 25 mm Pin Fin	1 m/s	5.6
Wakefield, 53 × 53 × 25 mm Pin Fin	2 m/s	5.1
MEI, 75 × 85 × 12 no adjacent board, extrusion	Natural Convection	9.0
MEI, 75 × 85 × 12 no adjacent board, extrusion	1 m/s	5.7
MEI, 75 × 85 × 12 no adjacent board, extrusion	2 m/s	5.1

Accurate thermal design requires thermal modeling of the application environment using computational fluid dynamics software which can model both the conduction cooling and the convection cooling of the air moving through the application. Simplified thermal models of the packages can be assembled using the junction-to-case and junction-to-board thermal resistances listed in the thermal resistance table. More detailed thermal models can be made available on request.

Heat sink vendors include the following:

Aavid Thermalloy 603-224-9988
80 Commercial St.
Concord, NH 03301
Internet: www.aavidthermalloy.com

Alpha Novatech 408-749-7601
473 Sapena Ct. #15
Santa Clara, CA 95054
Internet: www.alphanovatech.com

International Electronic Research Corporation (IERC) 818-842-7277
413 North Moss St.
Burbank, CA 91502
Internet: www.ctscorp.com

Millennium Electronics (MEI) Loroco Sites 671 East Brokaw Road San Jose, CA 95112 Internet: www.mei-millennium.com	408-436-8770
Tyco Electronics Chip Coolers™ P.O. Box 3668 Harrisburg, PA 17105-3668 Internet: www.chipcoolers.com	800-522-6752
Wakefield Engineering 33 Bridge St. Pelham, NH 03076 Internet: www.wakefield.com	603-635-5102

Interface material vendors include the following:

Chomerics, Inc. 77 Dragon Ct. Woburn, MA 01888-4014 Internet: www.chomerics.com	781-935-4850
Dow-Corning Corporation Dow-Corning Electronic Materials 2200 W. Salzburg Rd. Midland, MI 48686-0997 Internet: www.dowcorning.com	800-248-2481
Shin-Etsu MicroSi, Inc. 10028 S. 51st St. Phoenix, AZ 85044 Internet: www.microsi.com	888-642-7674
The Bergquist Company 18930 West 78th St. Chanhassen, MN 55317 Internet: www.bergquistcompany.com	800-347-4572

23.3 Heat Sink Attachment

When attaching heat sinks to these devices, an interface material is required. The best method is to use thermal grease and a spring clip. The spring clip should connect to the printed-circuit board, either to the board itself, to hooks soldered to the board, or to a plastic stiffener. Avoid attachment forces which would lift the edge of the package or peel the package from the board. Such peeling forces reduce the solder joint lifetime of the package. Recommended maximum force on the top of the package is 10 lb force (4.5 kg force). If an adhesive attachment is planned, the adhesive should be intended for attachment to painted or plastic surfaces and its performance verified under the application requirements.

26 Document Revision History

Table 80 provides a revision history for this hardware specification.

Table 80. Revision History

Rev. Number	Date	Substantive Change(s)
3	01/2011	• Updated references to the LCRR register throughout • Removed references to DDR DLL mode in Section 6.2.2, “DDR and DDR2 SDRAM Output AC Timing Specifications.” • Changed “Junction-to-Case” to “Junction-to-Ambient” in Section 23.2.4, “Heat Sinks and Junction-to-Ambient Thermal Resistance,” and Table 76, “Heat Sinks and Junction-to-Ambient Thermal Resistance of PBGA Package,” titles.
2	03/2010	• Changed references to RCWH[PCICKEN] to RCWH[PCICKDRV]. • In Table 2, added extended temperature characteristics. • Added Figure 5, “DDR Input Timing Diagram.” • In Figure 52, “Mechanical Dimensions and Bottom Surface Nomenclature of the PBGA Package,” removed watermark. • In Table 4, “MPC8358E PBGA Core Power Dissipation[1],” added row for 400/266/400 part offering. • Updated the title of Table 18,”DDR SDRAM Input AC Timing Specifications.” • In Table 19, “DDR and DDR2 SDRAM Input AC Timing Specifications Mode,” changed table subtitle. • In Table 26–Table 29, and Table 32—Table 33, changed the rise and fall time specifications to reference 20–80% and 80–20% of the voltage supply, respectively. • In Table 37, “IEEE 1588 Timer AC Specifications,” changed first parameter to “Timer clock frequency.” • In Table 44, “I2C AC Electrical Specifications,” changed units to “ns” for t_{I2DVKH}. • In Table 65 “MPC8358E PBGA Pinout Listing, added note 7: “This pin must always be tied to GND” to the TEST pin. • In Table 67, “Operating Frequencies for the PBGA Package,” and Table 78, “Part Numbering Nomenclature,” updated for 400 MHz QE part offering • In Section 4, “Clock Input Timing,” added note regarding rise/fall time on QUICC Engine block input pins. • Added Section 4.3, “Gigabit Reference Clock Input Timing.” • Updated Section 8.1.1, “10/100/1000 Ethernet DC Electrical Characteristics.” • In Section 21.3, “Pinout Listings,” added sentence stating “Refer to AN3097, ‘MPC8360/MPC8358E PowerQUICC Design Checklist,’ for proper pin termination and usage.” • In Section 22, “Clocking,” removed statement: “The OCCR[PCICDn] parameters select whether CLKIN or CLKIN/2 is driven out on the PCI_CLK_OUTn signals.” • In Section 22.1, “System PLL Configuration,” updated the system VCO frequency conditions. • In Table 78, added extended temperature characteristics.
1	12/2007	Initial release.